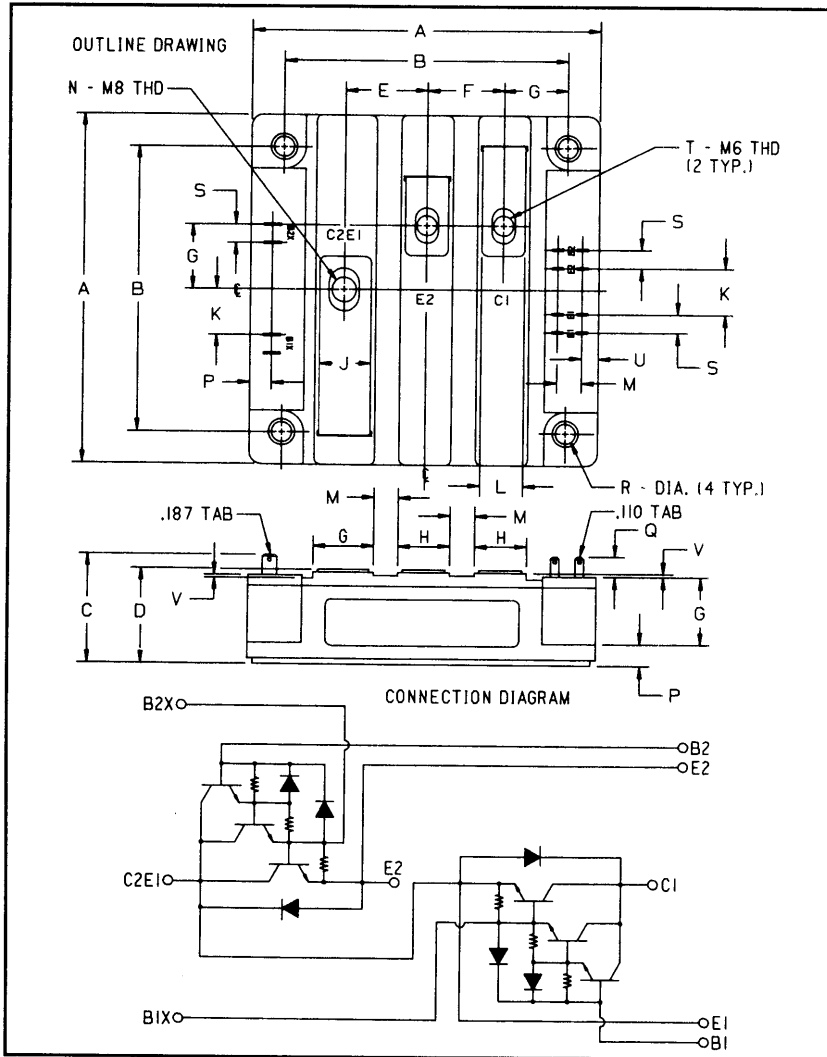


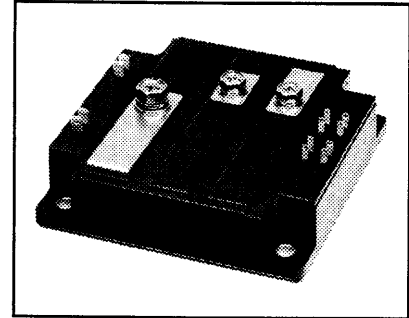
Dual Darlington Transistor Module 300 Amperes/1200 Volts



Outline Drawing

Dimensions	Inches	Millimeters
A	4.488 Max.	114 Max.
B	3.661 ± 0.012	93 ± 0.3
C	1.358	34.5
D	1.220 Max.	31 Max.
E	1.063	27
F	0.984	25
G	0.827	21
H	0.669	17
J	0.630	16
K	0.591	15

Dimensions	Inches	Millimeters
L	0.551	14
M	0.315	8
N	M8 Metric	M8
P	0.276	7
Q	0.256 Min.	6.5 Min.
R	0.256 Min.	6.5 Min.
S	0.236	6
T	M6 Metric	M6
U	0.216	5.5
V	0.039	1



Description:

The Powerex Dual Darlington Transistor Modules are high power devices designed for use in switching applications. The modules are isolated, consisting of two Darlington Transistors with each transistor having a reverse parallel connected high-speed diode.

Features:

- ☐ Isolated Mounting
- ☐ Planar Chips
- ☐ Discrete Fast Recovery Feedback Diode
- ☐ High Gain (h_{FE})
- ☐ Quick Connect Base-Emitter Signal Terminals
- ☐ Base-Emitter Speed-up Diodes

Applications:

- ☐ AC Motor Control
- ☐ DC Motor Control
- ☐ Switching Power Supplies
- ☐ Inverters

Ordering Information:

Example: Select the complete eight digit module part number you desire from the table - i.e. KD621230 is a 1200 Volt, 300 Ampere Dual Darlington Module.

Type	$V_{CE0(sus)}$ Volts (X 100)	Current Rating Amperes (X 10)
KD62	12	30



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (412) 925-7272

KD621230
Dual Darlington Transistor Module
 300 Amperes/1200 Volts

Absolute Maximum Ratings, $T_j = 25^\circ\text{C}$ unless otherwise specified

Ratings	Symbol	KD621230	Units
Junction Temperature	T_j	-40 to 150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to 125	$^\circ\text{C}$
Collector-Emitter Sustaining Voltage, $V_{BE} = -2\text{V}$	$V_{CEV(\text{sus})}$	1200	Volts
Collector-Base Voltage	V_{CBO}	1200	Volts
Emitter-Base Voltage	V_{EBO}	7	Volts
Collector-Emitter Voltage, $V_{BE} = -2\text{V}$	V_{CEV}	1200	Volts
Continuous Collector Current	I_C	300	Amperes
Diode Forward Current	I_{FM}	300	Amperes
Continuous Base Current	I_B	16	Amperes
Diode Surge Current	I_{FSM}	3000	Amperes
Power Dissipation (Each Transistor)	P_t	1980	Watts
Max. Mounting Torque M6 Terminal Screws	—	26	in.-lb.
Max. Mounting Torque M6 Mounting Screws	—	26	in.-lb.
Module Weight (Typical)	—	1200	Grams
V Isolation	V_{RMS}	2500	Volts

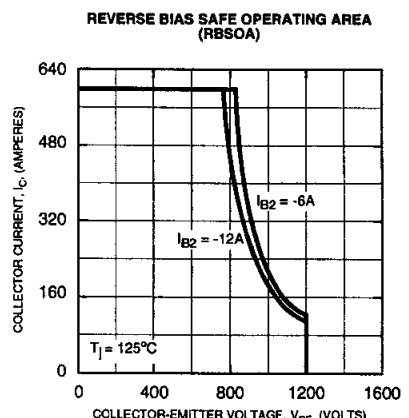
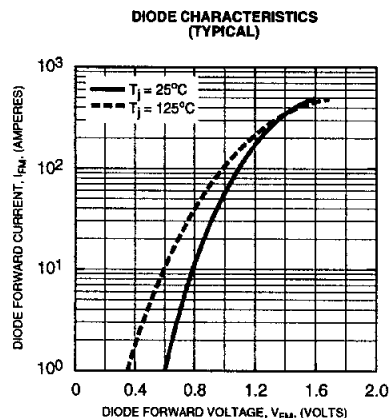
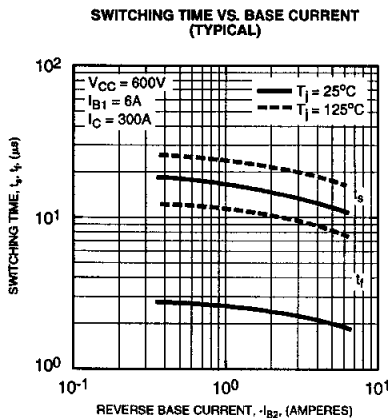
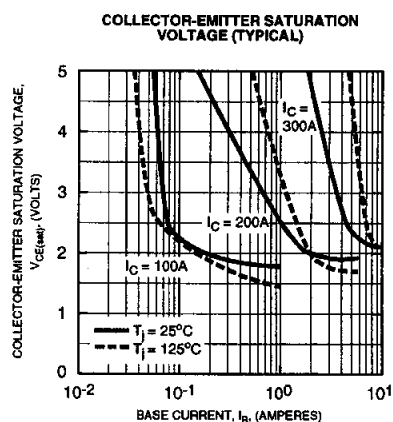
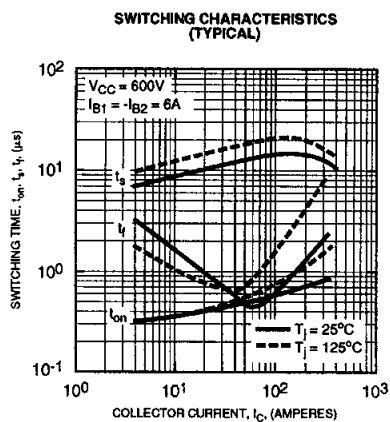
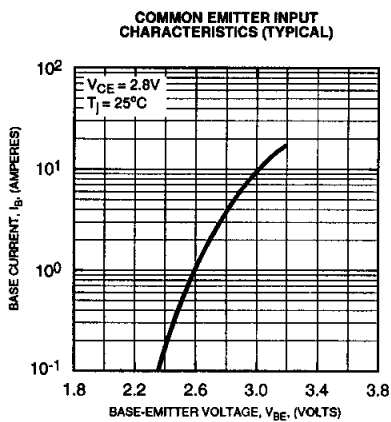
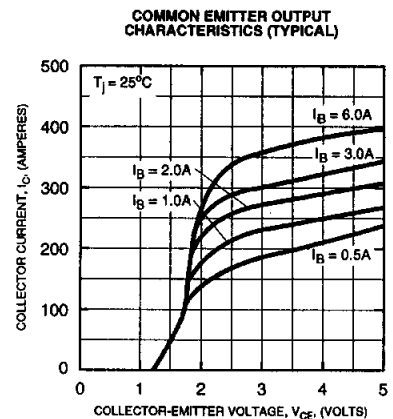
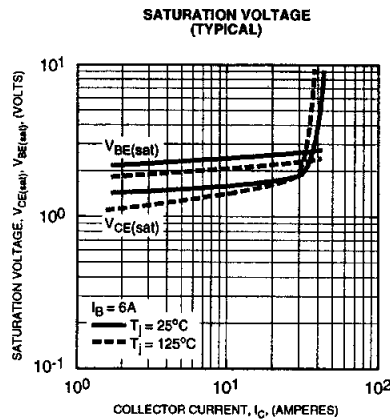
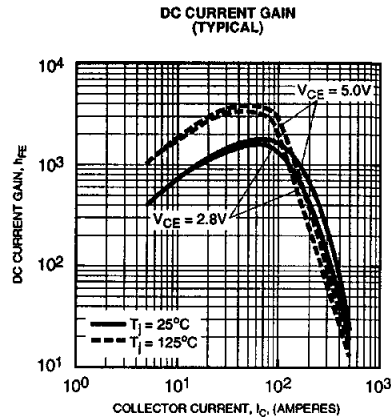
Electrical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector Cutoff Current	I_{CEV}	$V_{CE} = 1200\text{V}, V_{BE} = -2\text{V}$	—	—	4	mA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = 7\text{V}$	—	—	800	mA
DC Current Gain	h_{FE}	$I_C = 300\text{A}, V_{CE} = 5\text{V}$	75	—	—	—
Diode Forward Voltage	V_{FM}	$I_{FM} = 300\text{A}$	—	—	1.8	Volts
Collector-Emitter Saturation Voltage	$V_{CE(\text{sat})}$	$I_C = 300\text{A}, I_B = 6\text{A}$	—	—	3.0	Volts
Base-Emitter Saturation Voltage	$V_{BE(\text{sat})}$	$I_C = 300\text{A}, I_B = 6\text{A}$	—	—	3.5	Volts
Resistive Turn-on	t_{on}	$V_{CC} = 600\text{V}$	—	—	3.0	μs
Load Storage Time	t_s	$I_C = 300\text{A}$	—	—	15	μs
Switch Times Fall Time	t_f	$I_{B1} = -I_{B2} = 6\text{A}$	—	—	3.0	μs

Thermal and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Junction-to-Case	$R_{\theta(j-c)}$	Transistor Part	—	—	0.063	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	$R_{\theta(j-c)}$	Diode Part	—	—	0.3	$^\circ\text{C/W}$

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